

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT223 surface-mountable plastic package intended for applications requiring direct interfacing to logic level ICs and low power gate drivers.

2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drive circuits
- · High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Surface-mountable package
- Triggering in all four quadrants
- · Very sensitive gate in four quadrants

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{DRM}	repetitive peak off-state voltage				800		V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>			1		A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5			8		A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms			8.5		А
Tj	junction temperature				125		°C
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 9</u>		-	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 9}$		-	-	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u>		-	-	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 9</u>		-	-	5	mA

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>		-	-	7	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 12</u>		-	1.3	1.6	V
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 110 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit; Fig. 14		10	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	V_{D} = 400 V; T _j = 110 °C; dI _{com} /dt = 0.44 A/ms; gate open circuit		0.5	-	-	V/µs

5. Pinning information

Table 2. Pinn	ning information
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Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		Ν
2	T2	main terminal 2		
3	G	gate		sym051
4	T2	main terminal 2		

6. Ordering information

Table 3. Ordering in	iormation					
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
Z0103NN	SOT223	Z0103NN,135	Reel	4000	SOT223	16-Mar-2006

7. Marking

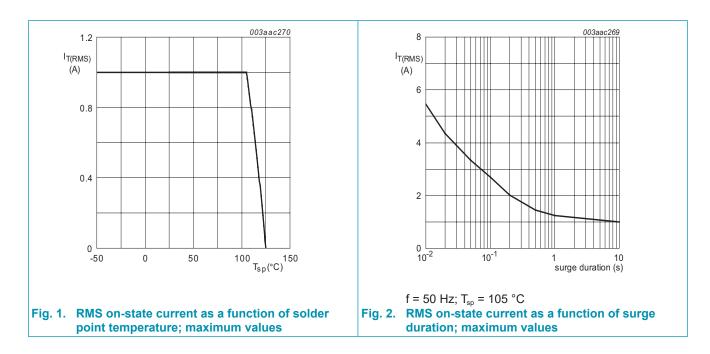
Type number	Marking codes		
	Assembly factory: L	Assembly factory: d	
Z0103NN	JLxxx 0103NN	Jdxxx 0103NN	

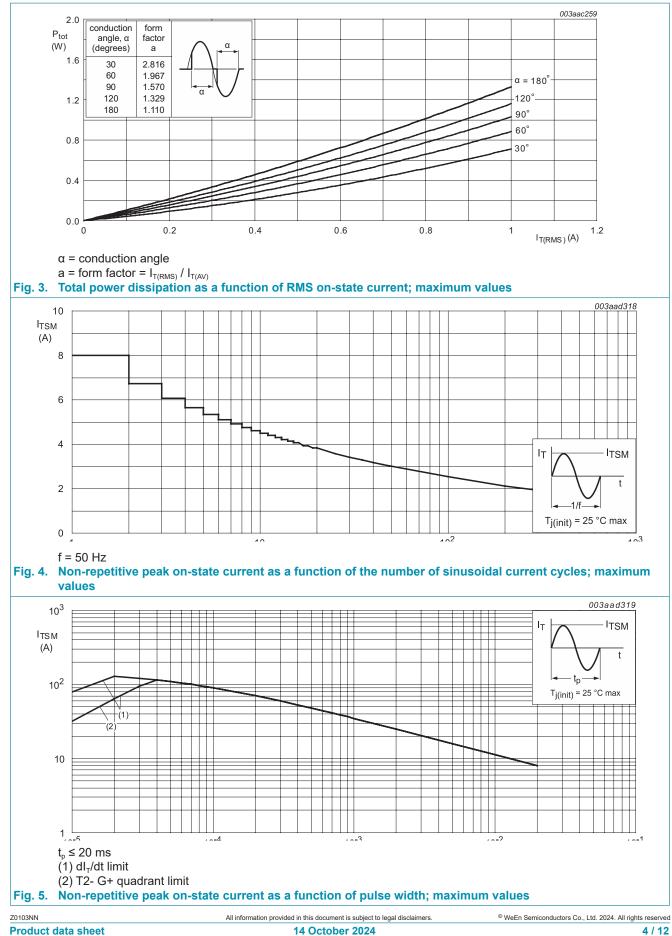
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
$I_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _{sp} ≤ 105 °C; <u>Fig 1; Fig 2; Fig 3</u>		1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5		8	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms		8.5	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN		0.32	A ² s
dl _⊤ /dt		I _G = 20 mA; T2+ G+		50	A/µs
	current	I _G = 20 mA; T2+ G-		50	A/µs
		I _G = 20 mA; T2- G-		50	A/µs
		I _G = 20 mA; T2- G+		20	A/µs
I _{GM}	peak gate current			1	А
P_{GM}	peak gate power			2	W
$P_{G(AV)}$	average gate power	over any 20 ms period		0.1	W
T _{stg}	storage temperature			-40 to 150	°C
Tj	junction temperature			125	°C





9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	full cycle; <u>Fig 6</u>		-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	full cycle; printed circuit board mounted; minimum footprint; Fig 7		-	156	-	K/W
		full cycle; printed circuit board mounted; pad area; Fig 8		-	70	-	K/W

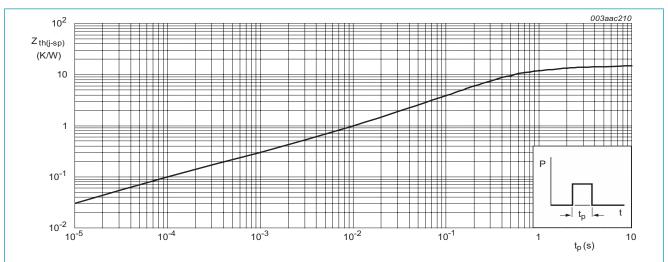
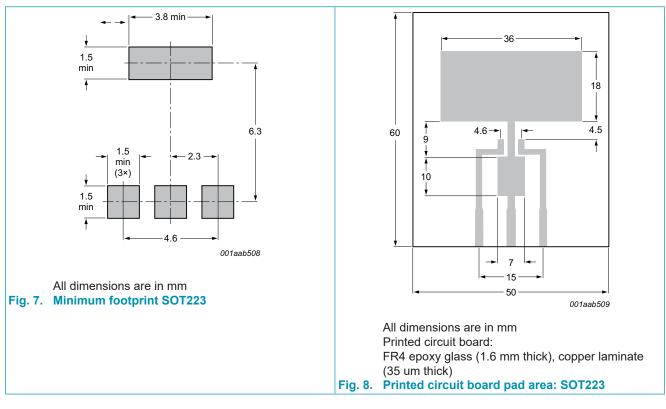


Fig. 6. Transient thermal impedance from junction to solder point as a function of pulse width

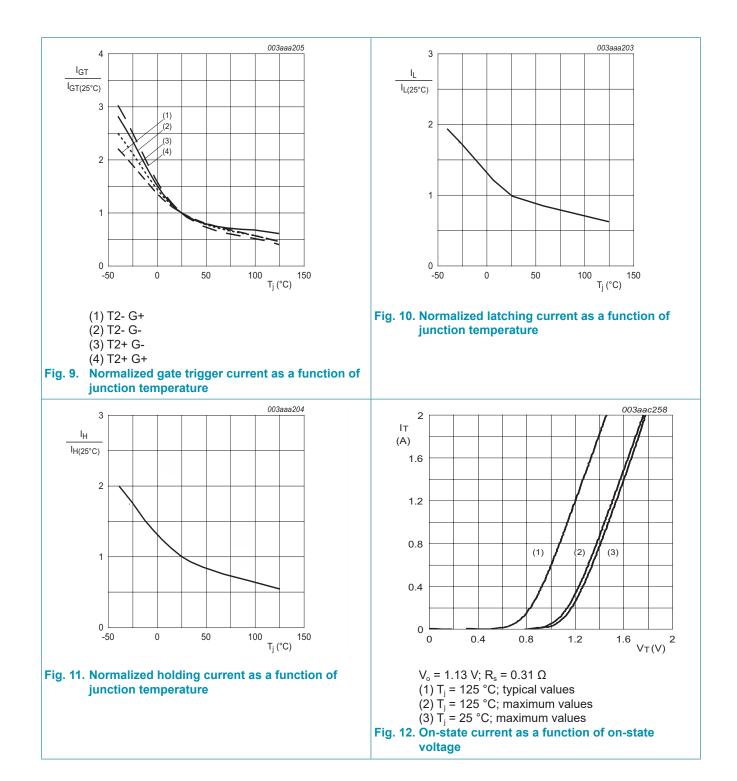


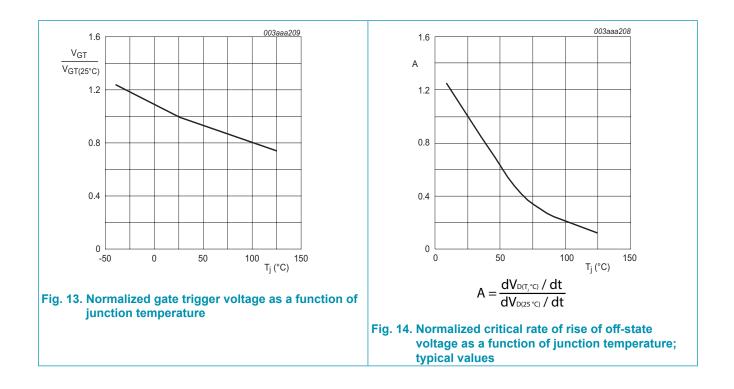
10. Characteristics

Table 7. Characteristics

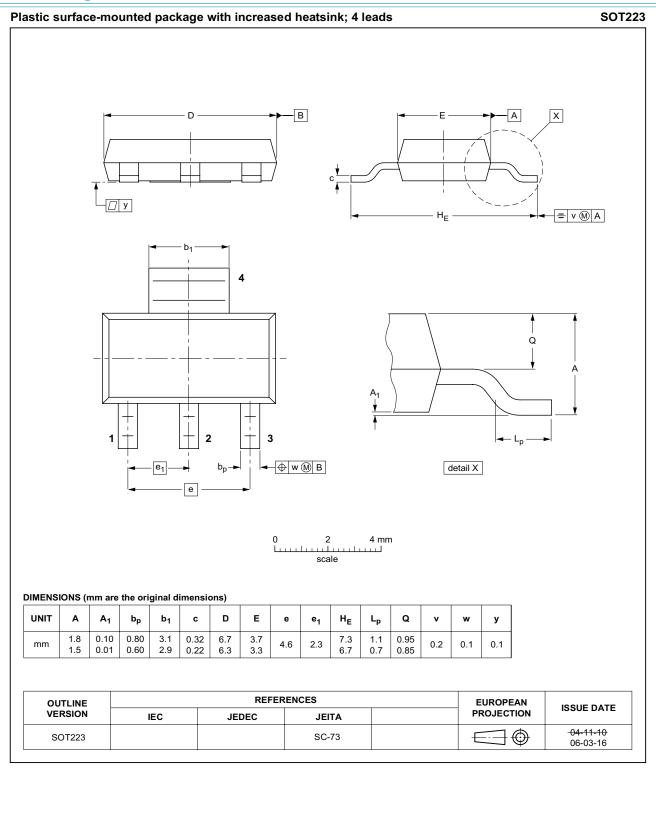
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						_
I _{GT} gate trigger current	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	5	mA
I _L	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 10		-	-	7	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 10		-	-	15	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 10</u>		-	-	7	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G+; T _j = 25 °C; Fig. 10		-	-	7	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>		-	-	7	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 12</u>		-	1.3	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 13		-	-	1	V
		V _D = 800 V; I _T = 0.1 A; T _j = 125 °C; Fig. 13		0.2	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C		-	-	0.5	mA
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 110 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 14		10	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 ^{\circ}\text{C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$		0.5	-	-	V/µs

Z0103NN 4Q Triac





11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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